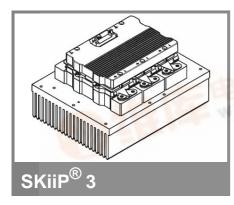
捷多邦,专业PCB打样工厂,24小时加急出货

SKiiP 1513GB172-3DL



2-pack-integrated intelligent Power System

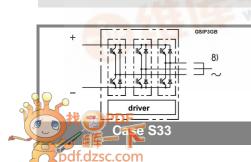
Power section

SKiiP 1513GB172-3DL

Preliminary Data

Features

- SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated teperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP[®] 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- AC connection busbars must be connected by the user; copper busbars available on request



Absolute Maximum Ratings T _s = 25 °C, unless otherwise specifie							
Symbol Conditions		Values	Units				
IGBT	12 10 1						
V _{CES}	Mag	1700	V				
V _{CES} V _{CC} ¹⁾	Operating DC link voltage	1200	V				
V _{GES}		± 20	V				
I _C	T _s = 25 (70) °C	1500 (1125)	Α				
Inverse diode							
I _F = - I _C	T _s = 25 (70) °C	1250 (950)	A				
I _{FSM}	T _j = 150 °C, t _p = 10 ms; sin	10200	A				
I²t (Diode)	Diode, T _j = 150 °C, 10 ms	520	kA²s				
T _j , (T _{stg})		- 40 + 150 (125)	°C				
V _{isol}	rms, AC, 1 min, m <mark>ain termin</mark> als to heat sink	4000	V				
I _{AC-terminal}	per AC terminal, rms, T _s = 70 °C,	400	А				
77	T _{terminal} < 115 °C						

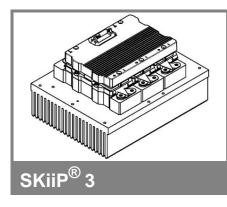
Characteristics		T_s = 25 °C, unless otherwise specifi			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
V _{CEsat}	$I_{C} = 900 \text{ A}, T_{j} = 25 (125) \text{ °C};$ measured at terminal	= E	1,9 (2,2)	2,4	V
V _{CEO}	T _i = 25 (125) °C; at terminal	ALC: W	1 (0,9)	1,2 (1,1)	V
r _{CE}	T _i = 25 (125) °C; at terminal	1000	1 (1,4)	1,3 (1,7)	mΩ
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES} , T _i = 25 (125) °C		3,6 (216)		mA
E _{on} + E _{off}	I _C = 900 A, V _{CC} = 900 V		585		mJ
LIVI.DZ	T _j = 125 °C, V _{CC} = 1200 V		863		mJ
R _{CC+EE} '	terminal chip, T _i = 25 °C		0,17		mΩ
L _{CE}	top, bottom		4		nH
C _{CHC}	per phase, AC-side		5,1		nF
Inverse o	Inverse diode				
V _F = V _{EC}	$I_F = 900 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ measured at terminal	E B	2 (1,8)	2,15	V
V _{TO}	T _i = 25 (125) °C		1,1 (0,8)	1,2 (0,9)	V
r _T	T _i = 25 (125) °C		1 (1,1)	1,1 (1,2)	mΩ
Err	$I_{\rm C} = 900 {\rm A}, {\rm V}_{\rm CC} = 900 {\rm V}$		108		mJ
5 24	T _j = 125 °C, V _{CC} = 1200 V		128		mJ
Mechani	cal data	•			
M _{dc}	DC terminals, SI Units	6		8	Nm
M _{ac}	AC terminals, SI Units	13		15	Nm
w	SKiiP [®] 3 System w/o heat sink		2,4		kg
w	heat sink	1.1	7,5	2200	kg

Thermal characteristics (PX 16 heat sink with fan SKF16B-230-1); "s" reference to heat sink; "r" reference to built-in temperature sensor (acc.IEC 60747-15)

R _{th(j-s)I}	per IGB	т					0,02	K/W	
R _{th(j-s)D}	per dioc	le					0,038	K/W	
Z _{th}	R _i (mK/W) (max. values)				tau _i (s)				
WW.DE	1	2	3	4	1	2	3	4	
Z _{th(j-r)I}	3,4	9,6	7	0	363	0,18	0,04	1	
Z _{th(j-r)D}	12	12	18	20	30	5	0,25	0,04	
Z _{th(r-a)}	2,1	20	5,5	1,4	210	85	11	0,4	

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SKiiP 1513GB172-3DL



2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 1513GB172-3DL

Preliminary Data

Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute Maximum Ratings		Т _а	$T_a = 25 \text{ °C}$, unless otherwise specified			
Symbol	Conditions		Values	Units		
V _{S2}	unstabilized 24 V power supply		30	V		
V _i	input signal voltage (high)		15 + 0,3	V		
dv/dt	secondary to primary side		75	kV/µs		
V _{isollO}	input / output (AC, rms, 2 s)		4000	V		
VisoIPD	partial discharge extinction voltage, rms, $Q_{PD} \le 10 \text{ pC}$;		1500	V		
V _{isol12}	output 1 / output 2 (AC, rms, 2 s)		1500	V		
f _{sw}	switching frequency		9	kHz		
f _{out}	output frequency for I=I _C ; sin.		1	kHz		
T _{op} (T _{stg})	operating / storage temperature		- 40 + 85	°C		

Characte	eristics	(T _a =			= 25 °C)
Symbol	Conditions	min.	typ.	max.	Units
V _{S2}	supply voltage non stabilized	13	24	30	V
I _{S2}	V _{S2} = 24 V	380+34*f/kHz+0,00015*(I _{AC} /A) ²			mA
V _{iT+}	input threshold voltage (High)			12,3	V
V _{iT-}	input threshold voltage (Low)	4,6			V
R _{IN}	input resistance		10		kΩ
CIN	input capacitance		1		nF
t _{d(on)IO}	input-output turn-on propagation time input-output turn-off propagation time		1,3 1,3		μs µs
t _{d(off)IO} t _{pERRRESET}	error memory reset time		9		μs
t _{TD}	top / bottom switch interlock time		3,3		μs
l _{analogOUT}	max. 5 mA; 8 V corresponds to 15 V supply voltage for external components		1500		A
I _{s1out}	max. load current			50	mA
I _{TRIPSC}	over current trip level (I _{analog} OUT = 10 V)	110	1875	400	A
T _{tp} U _{DCTRIP}	over temperature protection U _{DC} -protection (U _{analog OUT} = 9 V);	110	not implemented	120 d	°C V
	(option for GB types)				

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